

General Description

This product family offers state of the art performance. It is designed for high frequency applications where high efficiency and high reliability are required.

Features

- Low conduction loss due to low VF
- Extremely low switching loss by tiny Qc
- Highly rugged due to better surge current
- Industrial standard quality and reliability

Applications

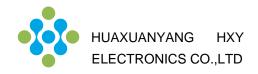
- UPS
- Power Inverter
- High performance SMPS
- Power factor correction

Ordering Part Number	Package	Marking	
HC1D20120G	TO-263-2L	HC1D20120G	









Maximum Ratings (at Tc = 25 °C, unless otherwise specified)

Parameter	Symbol	Value	Unit	
Repetitive Peak Reverse Voltage	V_{RRM}	1200	V	
Surge Peak Reverse Voltage	V_{RSM}	1200	V	
DC Peak Reverse Voltage	V_R	1200	V	
Continuous Forward Current				
$T_C = 25^{\circ}C$		54	_	
T _C = 135°C	l _F	27	Α	
$T_C = 153$ °C		20		
Repetitive Peak Forward Surge Current				
$T_C = 25$ °C, t_p =10ms,Half Sine Pulse	I _{FRM}	86	Α	
$T_C = 110^{\circ}C$, $t_p = 10$ ms, H alf Sine Pulse		58		
Non-Repetitive Forward Surge Current				
$T_C = 25$ °C, t_p =10ms,Half Sine Pulse	I _{FSM}	160	Α	
$T_C = 110^{\circ}C$, $t_p = 10$ ms, H alf Sine Pulse		130		
i ² dt value				
$T_C = 25$ °C, t_p =10ms,Half Sine Pulse	∫i ² dt	128	A^2s	
$T_C = 110^{\circ}C$, $t_p = 10$ ms, H alf Sine Pulse		84		
Power dissipation				
$T_C = 25$ °C	P _{tot}	214	W	
T _C = 110°C		93		
Operating junction Range	T _j	-55 to +175	°C	
Storage temperature Range	T_{stg}	-55 to +150	°C	

Thermal Resistance

Parameter	Symbol	Тур.	Unit
Thermal resistance, junction – case.	R_{thJC}	0.7	°C/W

Electrical Characteristics (at Tc = 25 °C, unless otherwise specified)

Parameter	Symbol	Value		Unit	Test Condition	
Faiailletei	Syllibol	min.	typ.	max.	Oilit	rest Condition
Forward Voltage	V _F				V	I _F =20A
		-	1.4	1.7		T _j =25°C
		-	2.0			T _j =175°C
	I _R				μΑ	V _R =1200V
Reverse Current		-	-	200		T _j =25°C
		-	-	400		T _j =175°C
Total Capacitive Charge	Q_{C}				nC	V _R =800V,T _j =25°C
		1	97	-		$Q_C = \int_0^{V_R} C(V) dV$
Total Capacitance	С				pF	T _j =25°C,f=1MHz
		-	1318	-		V _R =0V
		-	91	-		V _R =400V
		-	70	-		V _R =800V

Characteristics Curve

Fig 1: Forward Characteristics

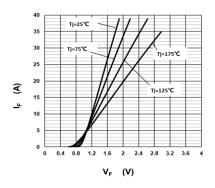


Fig 3: Current Derating

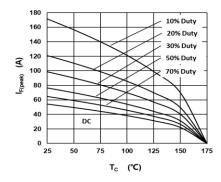


Fig 2: Reverse Characteristics

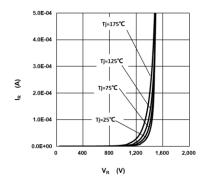


Fig 4: Power Derating

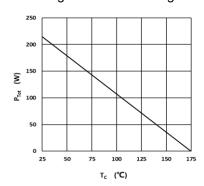


Fig 5: Capacitance vs. Reverse Voltage

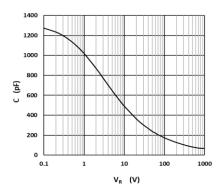


Fig 6: Reverse Charge vs. Reverse Voltage

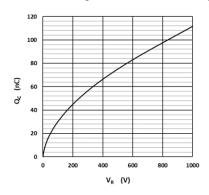


Fig 7: Typical Capacitance Stored Energy

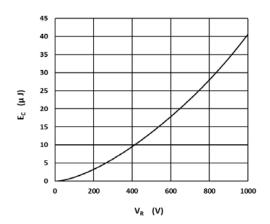
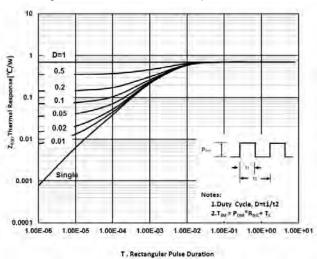
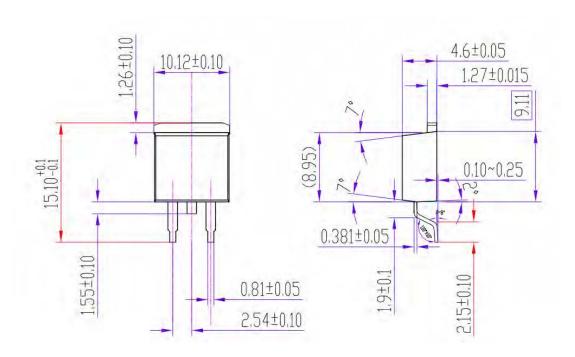


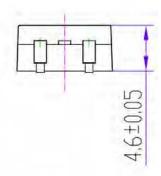
Fig 8: Transient Thermal Impandance

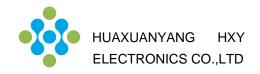


Package Dimensions

Package TO-263







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